

LSIC2SD120E20CC



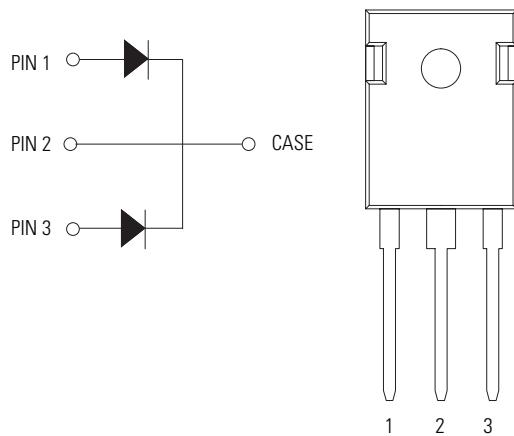
**Description**

This series of silicon carbide (SiC) Schottky diodes has negligible reverse recovery current, high surge capability, and a maximum operating junction temperature of 175 °C. These diodes series are ideal for applications where improvements in efficiency, reliability, and thermal management are desired.

**Features**

- Positive temperature coefficient for safe operation and ease of paralleling
- 175 °C maximum operating junction temperature
- Excellent surge capability
- Extremely fast, temperature-independent switching behavior
- Dramatically reduced switching losses compared to Si bipolar diodes

**Circuit Diagram TO247-3L**



**Applications**

- Boost diodes in PFC or DC/DC stages
- Switch-mode power supplies
- Uninterruptible power supplies
- Solar inverters
- Industrial motor drives
- EV charging stations

**Environmental**

- Littelfuse "RoHS" logo = RoHS conform
- Littelfuse "HF" logo = Halogen Free
- Littelfuse "PB-free" logo = Pb-free lead plating

**Maximum Ratings**

Characteristics	Symbol	Conditions	Value	Unit
Repetitive Peak Reverse Voltage	$V_{RRM}$	-	1200	V
DC Blocking Voltage	$V_R$	$T_J = 25\text{ °C}$	1200	V
Continuous Forward Current (Per Leg/Device)	$I_F$	$T_C = 25\text{ °C}$	28/56	A
		$T_C = 135\text{ °C}$	13.5/27	
		$T_C = 151\text{ °C}$	10/20	
Non-Repetitive Forward Surge Current (Per Leg)	$I_{FSM}$	$T_C = 25\text{ °C}, T_p = 10\text{ ms}, \text{Half sine pulse}$	80	A
Power Dissipation (Per Leg/Device)	$P_{Tot}$	$T_C = 25\text{ °C}$	136/272	W
		$T_C = 110\text{ °C}$	59/118	
Operating Junction Temperature	$T_J$	-	-55 to 175	°C
Storage Temperature	$T_{STG}$	-	-55 to 150	°C
Soldering Temperature	$T_{sold}$	-	260	°C

**Electrical Characteristics (Per Leg)**

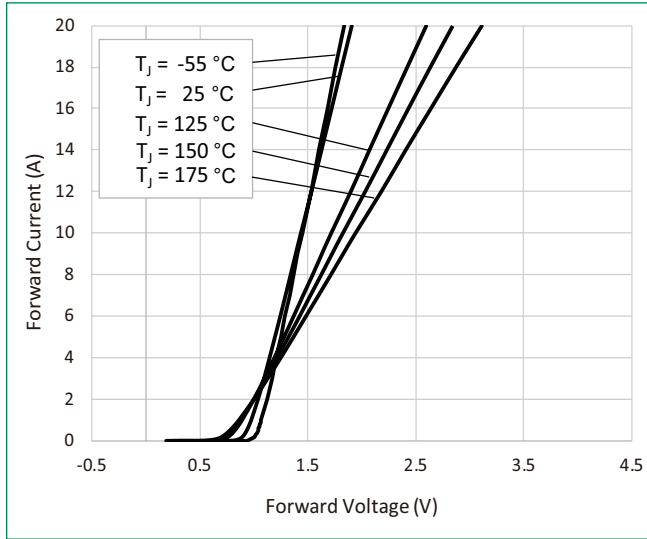
Characteristics	Symbol	Conditions	Value			Unit
			Min.	Typ.	Max.	
Forward Voltage	$V_F$	$I_F = 10\text{ A}, T_J = 25\text{ }^\circ\text{C}$	-	1.5	1.8	V
		$I_F = 10\text{ A}, T_J = 175\text{ }^\circ\text{C}$	-	2.2	-	
Reverse Current	$I_R$	$V_R = 1200\text{ V}, T_J = 25\text{ }^\circ\text{C}$	-	<1	100	$\mu\text{A}$
		$V_R = 1200\text{ V}, T_J = 175\text{ }^\circ\text{C}$	-	10	-	
Total Capacitance	C	$V_R = 1\text{ V}, f = 1\text{ MHz}$	-	582	-	pF
		$V_R = 400\text{ V}, f = 1\text{ MHz}$	-	53	-	
		$V_R = 800\text{ V}, f = 1\text{ MHz}$	-	40	-	
Total Capacitive Charge	$Q_C$	$V_R = 800\text{ V}, Q_C = \int_0^{V_R} C(V)dV$	-	57	-	nC

Footnote:  $T_J = +25\text{ }^\circ\text{C}$  unless otherwise specified

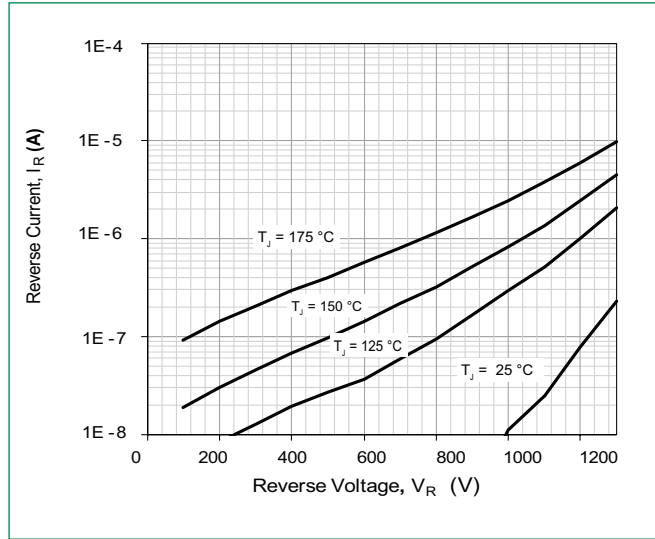
**Thermal Characteristics**

Characteristics	Symbol	Conditions	Value			Unit
			Min.	Typ.	Max.	
Thermal Resistance (Per Device/Leg)	$R_{\theta JC}$	-	-	1.10/0.55	-	$^\circ\text{C/W}$

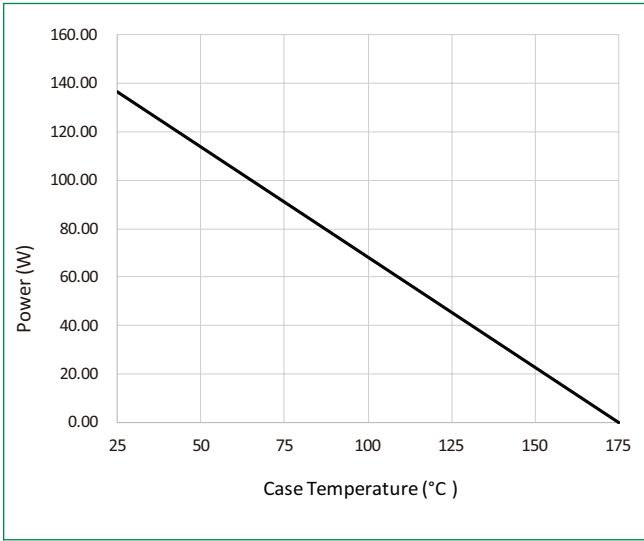
**Figure 1: Typical Forward Characteristics (Per Leg)**



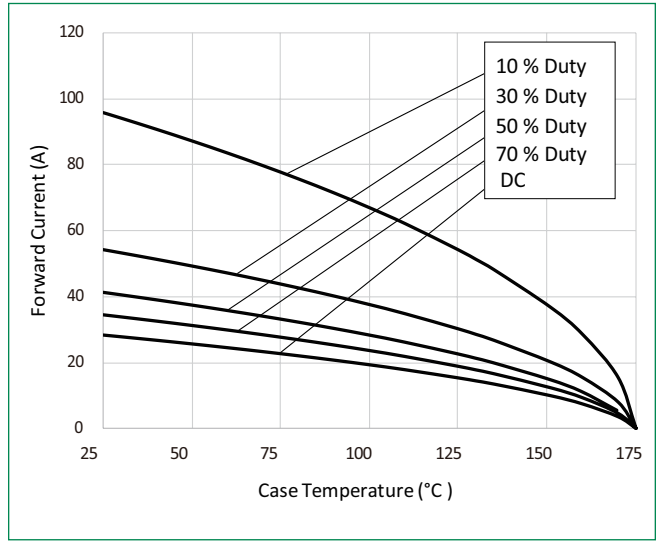
**Figure 2: Typical Reverse Characteristics (Per Leg)**



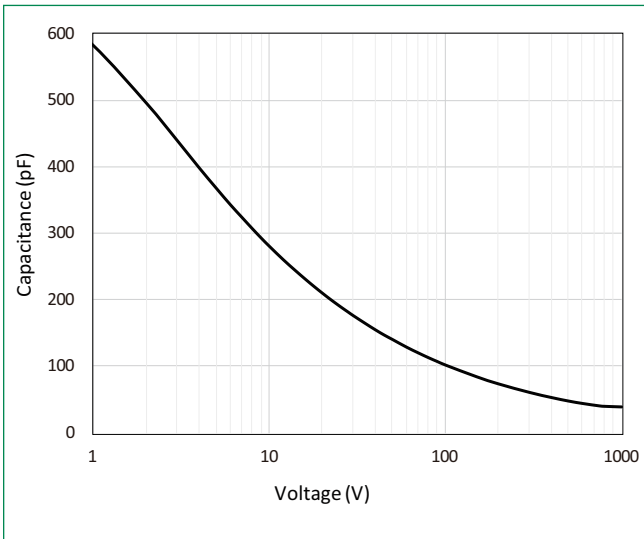
**Figure 3: Power Derating (Per Leg)**



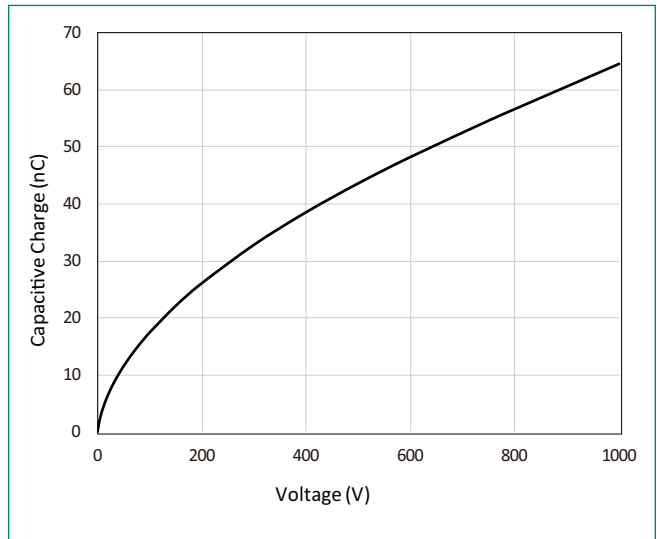
**Figure 4: Current Derating (Per Leg)**



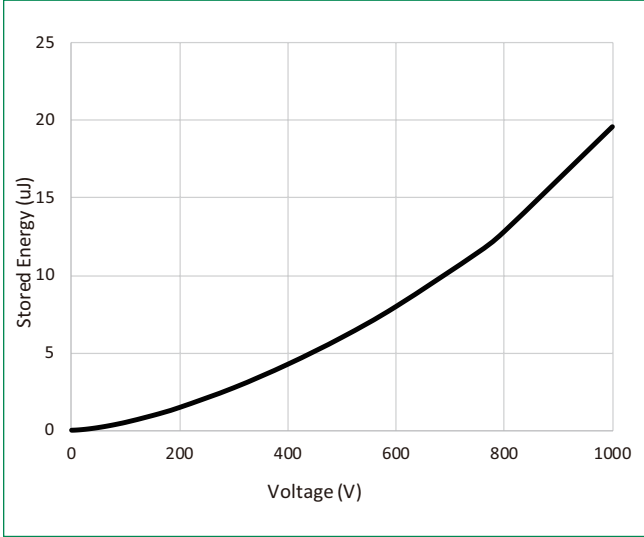
**Figure 5: Capacitance vs. Reverse Voltage (Per Leg)**



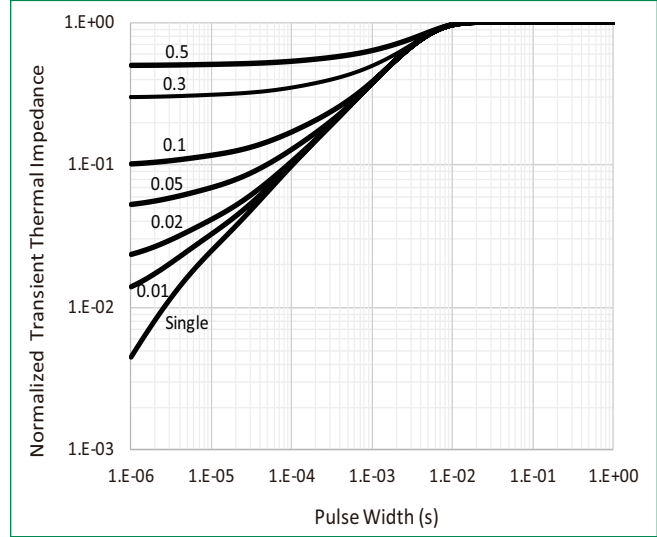
**Figure 6: Capacitive Charge vs. Reverse Voltage (Per Leg)**



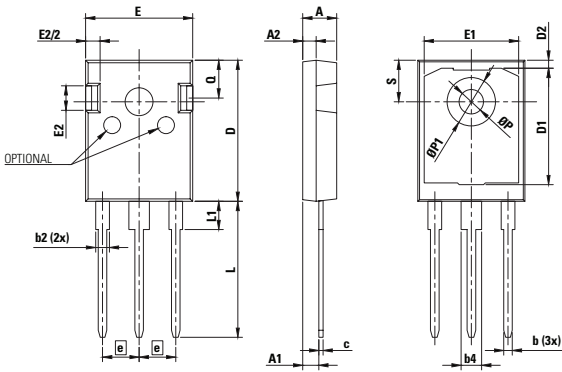
**Figure 7: Stored Energy vs. Reverse Voltage (Per Leg)**



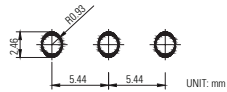
**Figure 8: Transient Thermal Impedance (Per Device)**



**Package Dimensions TO-247-3L**



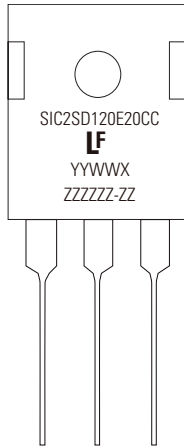
**Recommended Hole Pattern Layout**



- Notes:**
1. Dimensions are in millimeters
  2. Dimension D, E do not include mold flash. Mold flash shall not exceed 0.127 mm per side. These measured at the outermost extreme of plastic body.
  3.  $\phi P$  to have a maximum draft angle of 1.5° to the top of the part with a maximum hole diameter of 0.154"

Symbol	Millimeters		
	Min	Nom	Max
A	4.80	5.03	5.20
A1	2.25	2.38	2.54
A2	1.85	1.98	2.11
b	0.99	-	1.40
b2	1.65	-	2.39
b4	2.59	-	3.43
c	0.38	0.64	0.89
D	20.80	20.96	21.34
D1	13.50	-	-
D2	0.51	1.19	1.35
e	5.44 BSC		
E	15.75	15.90	16.13
E1	13.06	14.02	14.15
E2	4.19	4.32	4.83
L	19.81	20.19	20.57
L1	3.81	4.19	4.45
$\phi P$	3.55	3.61	3.66
$\phi P1$	7.06	7.19	7.32
Q	5.49	5.61	6.20
S	6.05	6.17	6.30

**Part Numbering and Marking System**

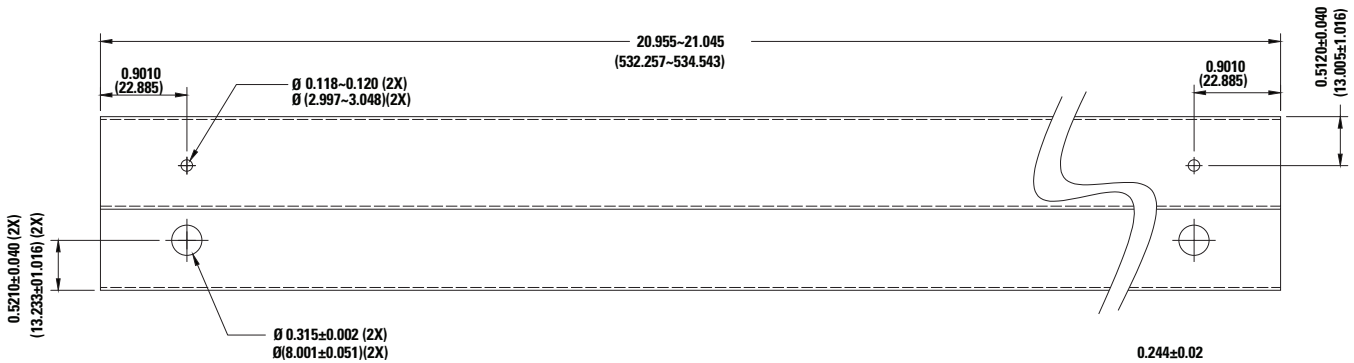


- SIC = SiC
- 2 = Gen2
- SD = Schottky Diode
- 120 = Voltage Rating (1200 V)
- E = TO-247-3L
- 20 = Current Rating ( 20 A)
- CC = Common Cathode
- YY = Year
- WW = Week
- X = Trace Code (Any Letter)
- ZZZZZZ-ZZ = Lot Number

**Packing Options**

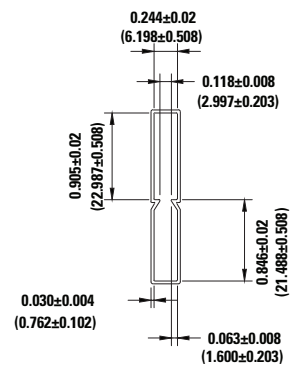
Part Number	Marking	Packing Mode	M.O.Q
LSIC2SD120E20CC	SIC2SD120E20CC	Tube	450

**Packing Specification TO-247-3L**



**NOTE:**

1. All pin plug holes are considered critical dimension
2. Tolerance is to be ±0.010 unless otherwise specified
3. Dimension are in inch (and millimeters).



**Disclaimer Notice** - Littelfuse products are not designed for, and shall not be used for, any purpose (including, without limitation, automotive, military, aerospace, medical, life-saving, life-sustaining or nuclear facility applications, devices intended for surgical implant into the body, or any other application in which the failure or lack of desired operation of the product may result in personal injury, death, or property damage) other than those expressly set forth in applicable Littelfuse product documentation. Warranties granted by Littelfuse shall be deemed void for products used for any purpose not expressly set forth in applicable Littelfuse documentation. Littelfuse shall not be liable for any claims or damages arising out of products used in applications not expressly intended by Littelfuse as set forth in applicable Littelfuse documentation. The sale and use of Littelfuse products is subject to Littelfuse Terms and Conditions of Sale, unless otherwise agreed by Littelfuse. Information furnished is believed to be accurate and reliable. However, users should independently evaluate the suitability of and test each product selected for their own applications. Littelfuse products are not designed for, and may not be used in, all applications. Read complete Disclaimer Notice at [www.littelfuse.com/disclaimer-electronics](http://www.littelfuse.com/disclaimer-electronics).